

## Photovoltaic Solar Cell Protection Schottky Diode

### **Features**

- Low power loss, high efficiency
- High surge current capabity
- Guardring for overvoltage potection
- High temperature reverse characteristic is excellent
- Trench Schottky Technology
- Metal of silicon rectifier, majority carrier conduction

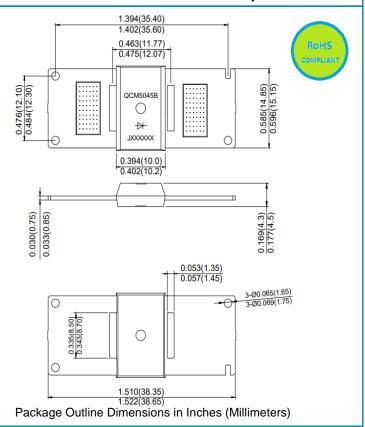
#### **Mechanical Data**

- Case:QC3Q, Molded plastic body Molding compound meets UL 94 V-0 flammability rating
- Terminal: Mattle tin plated leads, solderable per JESD22-B102
- Polarity: As marked on body
- Weight: 4.86grams(approximately)

## **Typical Applications**

- Photovoltaic solar cell protection
- Switching power supplies, converters, freewheeling diodes, and reverse battery protection

# Bypass Diode Module For PV Forward Current - 40 Amperes



### **Maximum Ratings and Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristics		SYM	QCM4045-150T1	Unit
Maximum Repetitive Peak Reverse Voltage		Vrrm	45	V
Maximum RMS Voltage		VRMS	31.5	V
Maximum DC Blocking Voltage		VDC	45	V
Maximum Average Forward Rectified Current @ Tc=125 $^{\circ}$ C		l(AV)	40	Α
Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load ( JEDEC Method )		IFSM	400	А
Peak Forward Voltage at	25A DC (Note 1)	VF	0.48	V
	40A DC (Note 1)		0.56	
Maximun DC Reverse Current at Rated DC Blocking Voltage	@TJ=25℃	lr lr	0.1	mA
	@TJ=100°C		15	
Typical Thermal Resistance Junction to Case		Rелс	1.5	°C/W
Junction Temperature Range ( Note2 )		TJ	-55 to+200	$^{\circ}$
Storage Temperature Range		Тѕтс	-55 to+150	$^{\circ}$

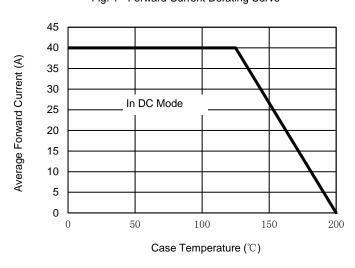
Notes: 1. 300uS pulse width, 2%duty cycle.

- 2. Junction Temperature In DC forward current without reverse bias, ,t≤1 h (Fig.1). Meets the Requirements of IEC 61215 Ed. 2 bypass diode thermal test.
  - 3. The typical data above is for reference only.
  - 4. Products made by JUXIN semiconductor



## **Rating and Characteristic Curves**

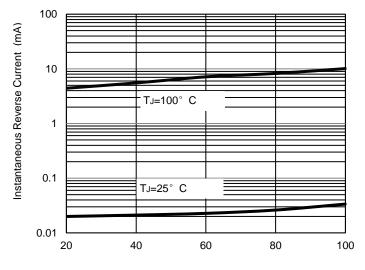
Fig. 1 - Forward Current Derating Curve



450
400
8.3mS Single Half-Sine-Wave (JEDEC METHOD)
350
250
200
150
100
1 10 100

Fig. 2 - Maximum Non-Repetitive Surge Current

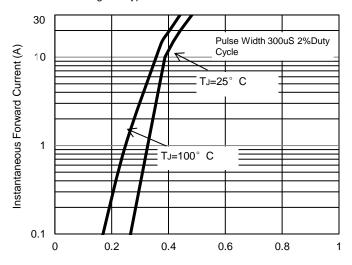
Fig. 3 - Typical Reverse Characteristics



Percent of Rated Peak Reverse Voltage (%)

Fig. 4 - Typical Forward Characteristics

Number of Cycles at 60Hz



Instantaneous Forward Voltage (V)